

2SA1648,1648-Z

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

DESCRIPTION

The 2SA1648 is a mold power transistor developed for high-speed switching and features a very low collector-to-emitter saturation voltage.

This transistor is ideal for use in switching regulators, DC/DC converters, motor drivers, solenoid drivers, and other low-voltage power supply devices, as well as for high-current switching.

FEATURES

- · Available for high-current control in small dimension
- Z type is a lead processed product and is deal for mounting a hybrid IC.
- Mold package that does not require an insulating board or insulation bushing.
- Low collector saturation voltage:

 $V_{CE(sat)1} = -0.3 \text{ V MAX.} (Ic = -3.0 \text{ A})$

· Fast switching speed:

 $t_f = 0.3 \ \mu s \ MAX. (Ic = -3.0 \ A)$

· High DC current gain and excellent linearity

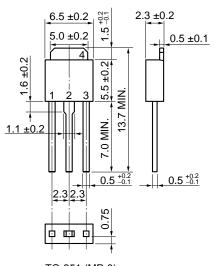
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	-100	V
Collector to emitter voltage	VCEO	-60	V
Base to emitter voltage	VEBO	-7.0	V
Collector current (DC)	Ic(DC)	-5.0	Α
Collector current (pulse)	IC(pulse) Note 1	-10	Α
Base current (DC)	B(DC)	-2.5	Α
Total power dissipation (Tc = 25°C)	Рт	18	W
Total power dissipation (T _A = 25°C)	PT	$1.0^{\text{Note 2}}, 2.0^{\text{Note 3}}$	W
Junction temperature	T_{j}	150	°C
Storage temperature	Tstg	-55 to +150	°C

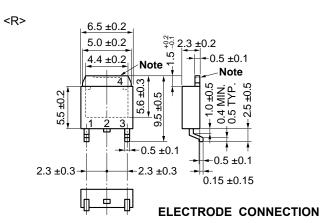
Notes 1. PW \leq 300 μ s, Duty Cycle \leq 10%

- 2. Printing board mounted
- 3. $7.5 \text{ cm}^2 \times 0.7 \text{ mm}$ ceramic board mounted

PACKAGE DRAWINGS (Unit: mm)



TO-251 (MP-3)



TO-252 (MP-3Z)

- 1. Base
- Collector
- 3. Emitter
- 4. Collector Fin

Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

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ELECTRICAL CHARACTERISTICS (TA = 25°C)

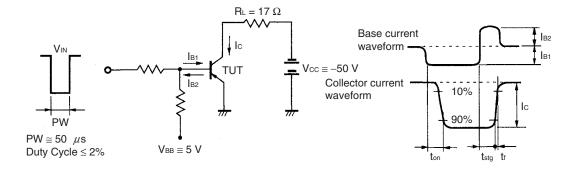
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = -3.0 A, Iв = -0.3 A, L = 1 mH	-60			V
Collector to emitter voltage	VCEX(SUS)	Ic = -3.0 A, IB2 = $-IB1$ = -0.3 A, VBE(OFF) = 1.5 V, L = 180 μ H, clamped				V
Collector cutoff current	Ісво	Vce = -60 V, Ie = 0 A			-10	μА
Collector cutoff current	ICER	$V_{CE}=-60~V,~R_{BE}=50~\Omega,~T_{A}=125^{\circ}C$			-1.0	mA
Collector cutoff current	ICEX1	$V_{CE} = -60 \text{ V}, V_{BE(OFF)} = 1.5 \text{ V}$			-10	μΑ
Collector cutoff current	ICEX2	$V_{CE} = -60 \text{ V}, V_{BE(OFF)} = 1.5 \text{ V},$ $T_A = 125^{\circ}C$			-1.0	mA
Emitter cutoff current	ІЕВО	V _{EB} = -5.0 V, I _C = 0 A			-10	μА
DC current gain	h _{FE1} Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			
DC current gain	hFE2 ^{Note}	Vce = -2.0 V, Ic = -1.0 A	100	200	400	
DC current gain	hfe3 ^{Note}	$V_{CE} = -2.0 \text{ V}, I_{C} = -3.0 \text{ A}$	60			
Collector saturation voltage	V _{CE(sat)1} Note	Ic = -3.0 A, IB = -0.15 A			-0.3	V
Collector saturation voltage	V _{CE(sat)2} Note	Ic = -4.0 A, IB = -0.2 A			-0.5	V
Base saturation voltage	V _{BE(sat)1} Note	$Ic = -3.0 \text{ A}, I_B = -0.15 \text{ A}$			-1.2	V
Base saturation voltage	V _{BE(sat)2} Note	Ic = -4.0 A, IB = -0.2 A			-1.5	V
Collector capacitance	Cob	$V_{CB} = -10 \text{ V}, I_E = 0 \text{ A}, f = 1.0 \text{ MHz}$		80		pF
Gain bandwidth product	f⊤	Vce = -10 V, Ic = 0.5 A		90		MHz
Turn-on time	ton	Ic = -3.0 A, R _L = 17 Ω ,			0.3	μs
Storage time	t stg	I _{B1} = -I _{B2} = -0.15 A, V _{CC} ≅ -50 V Refer to SWITCHING TIME TEST			1.5	μS
Fall time	tr	CIRCUIT.			0.3	μs

Note Pulse test PW \leq 350 μ s, Duty Cycle \leq 2%/Pulsed

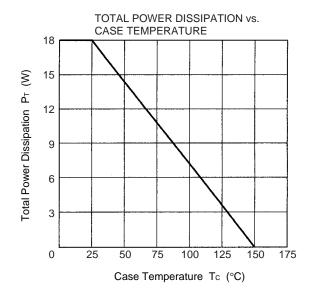
hfe CLASSIFICATION

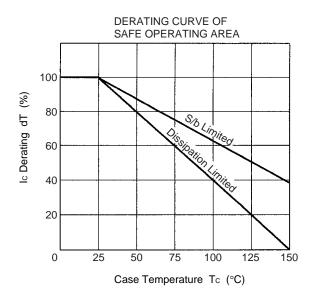
Marking	М	L	K
h _{FE2}	100 to 200	150 to 300	200 to 400

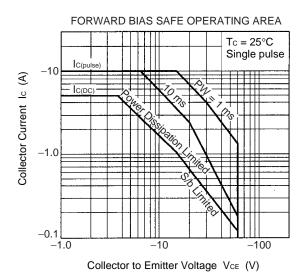
SWITCHING TIME TEST CIRCUIT

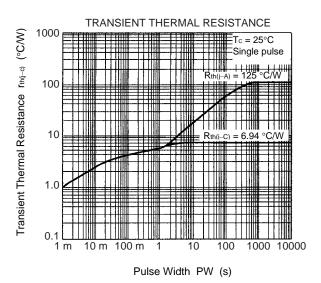


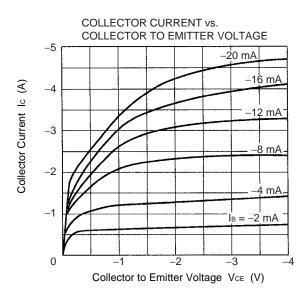
TYPICAL CHARACTERISTICS (TA = 25°C)

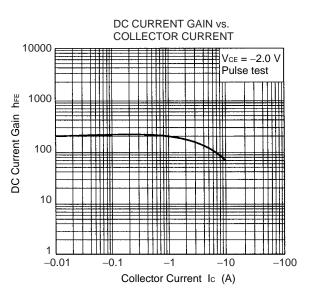


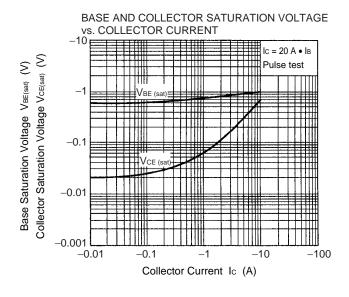


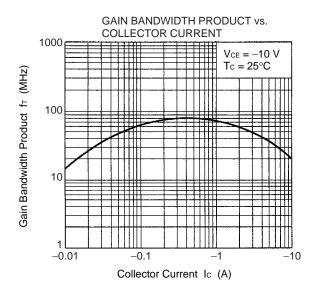


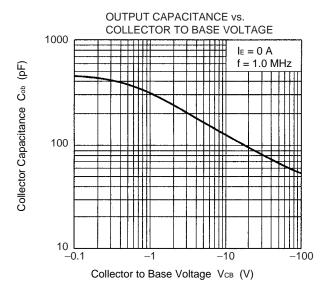


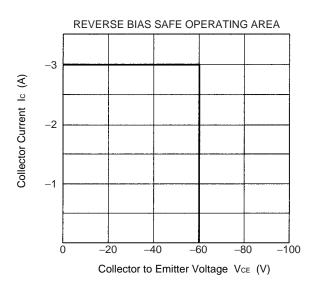


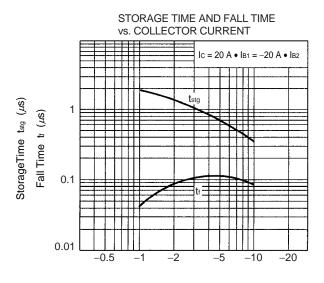












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